

# PMEG3015EV

30 V, 1.5 A ultra low  $V_{\text{F}}$  MEGA Schottky barrier rectifier in SOT666 package

Rev. 02 — 4 February 2010

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in an ultra small SMD SOT666 plastic package.

#### 1.2 Features

Forward current: 1.5 AReverse voltage: 30 V

Ultra low forward voltage

Ultra small SMD packages

## 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Voltage clamping
- Inverse polarity protection
- Low power consumption applications

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current	$T_{sp} \leq 55  ^{\circ}C$	-	-	1.5	Α
$V_R$	reverse voltage		-	-	30	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 1.5 A	<u>[1]</u> _	480	550	mV

[1] Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



# 2. Pinning information

Table 2. Pinning

	3		
Pin	Description	Simplified outline	Symbol
1	cathode		4.0
2	cathode	6 5 4	<sup>1, 2</sup> / <sub>5, 6</sub> 3, 4
3	anode		sym038
4	anode		
5	cathode	1 2 3	
6	cathode	1 2 3	

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG3015EV	-	plastic surface mounted package; 6 leads	SOT666

# 4. Marking

Table 4. Marking codes

Type number	Marking code
PMEG3015EV	1A

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{R}$	reverse voltage		-	30	V
I <sub>F</sub>	forward current	$T_{sp} \le 55  ^{\circ}C$	-	1.5	Α
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$	[1] -	4.5	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 8 ms; square wave	<u>[1]</u> _	9.5	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[2] -	0.31	W
			[3] _	0.58	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> For SOT666 only valid, if pins 3 and 4 are connected in parallel.

#### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1][2]			
			[3]	-	405	K/W
			<u>[4]</u> _	-	215	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	80	K/W

<sup>[1]</sup> For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses. Nomograms for determining the reverse power losses  $P_R$  and  $I_{F(AV)}$  rating will be available on request.

<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for cathode 1cm<sup>2</sup>.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[4]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for cathode 1cm<sup>2</sup>.

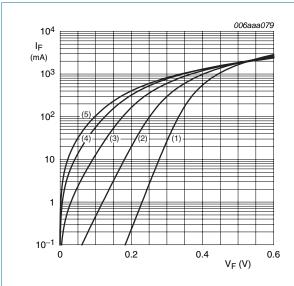
## 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

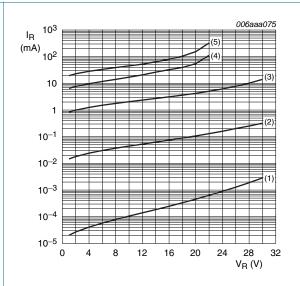
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 1 \text{ mA}$	<u>[1]</u> _	125	160	mV
		I <sub>F</sub> = 10 mA	<u>[1]</u> _	185	220	mV
		I <sub>F</sub> = 100 mA	<u>[1]</u> _	255	290	mV
		I <sub>F</sub> = 500 mA	<u>[1]</u> _	340	380	mV
		I <sub>F</sub> = 1 A	<u>[1]</u> _	410	480	mV
		I <sub>F</sub> = 1.5 A	<u>[1]</u> _	480	550	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	60	150	μΑ
		V <sub>R</sub> = 30 V	-	400	1000	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	60	72	pF

<sup>[1]</sup> Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 



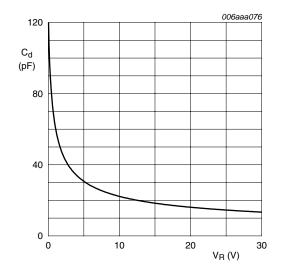
- (1)  $T_{amb} = -40 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 125 \, ^{\circ}C$
- (5)  $T_{amb} = 150 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = -40 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 125 \, ^{\circ}C$
- (5) T<sub>amb</sub> = 150 °C

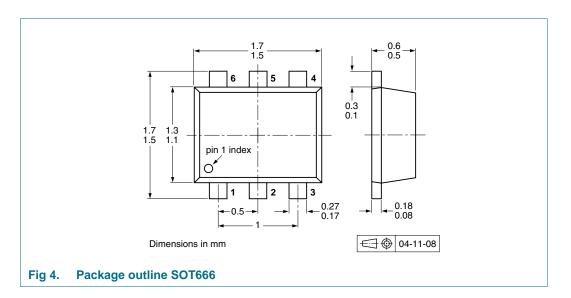
Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

# 8. Package outline



# 9. Packing information

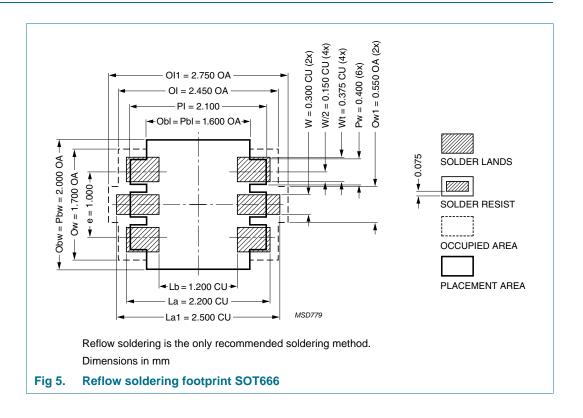
#### Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			4000
PMEG3015EV	SOT666	4 mm pitch, 8 mm tape and reel	-115

[1] For further information and the availability of packing methods, see Section 13.

# 10. Soldering





# 11. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3015EV_2	20100204	Product data sheet	-	PMEG3015EV_1
Modifications:		eet was changed to reflect w legal definitions and disc	· · ·	
PMEG3015EV_1	20050404	Product data sheet	-	-

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PMEG3015EV

## 30 V, 1.5 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier

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